6-Pin DIP High dv/dt Random Phase Triac Drivers

FOD420, FOD4208, FOD4216, FOD4218

Description

The FOD420, FOD4208, FOD4216 and FOD4218 devices consist of an infrared emitting diode coupled to a hybrid random phase triac formed with two inverse parallel SCRs which form the triac function capable of driving discrete triacs. The FOD4216 and FOD4218 utilize a high efficiency infrared emitting diode which offers an improved trigger sensitivity. These devices are housed in a standard 6-pin dual in-line (DIP) package.

Features

- 300 mApeak On-State Current
- High Blocking Voltage
 - 600 V (FOD420, FOD4216)
 - 800 V (FOD4208, FOD4218)
- High Trigger Sensitivity
 - 1.3 mA (FOD4216, FOD4218)
 - 2 mA (FOD420, FOD4208)
- High Static dv/dt (10,000 V/µs)
- Safety and Regulatory Approvals:
 - UL1577, 5,000 VAC_{RMS} for 1 Minute
 - ◆ DIN-EN/IEC60747-5-5
- These Devices are Pb-Free and are RoHS Compliant

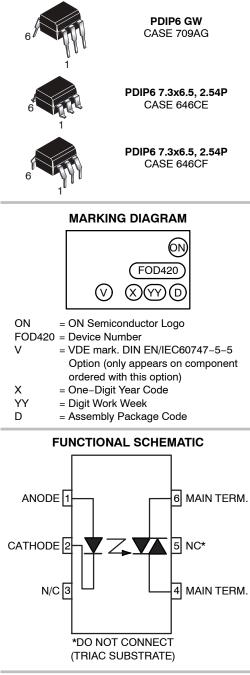
Applications

- Solid-State Relays
- Industrial Controls
- Lighting Controls
- Static Power Switches
- AC Motor Starters



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ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

SAFETY AND INSULATION RATINGS

Parameter	Characteristics	
Installation Classifications per DIN VDE 0110/1.89 Table 1, For Rated Mains Voltage	E 0110/1.89 Table 1, For Rated Mains Voltage < 150 V _{RMS}	
	< 300 V _{RMS}	I–IV
Climatic Classification		55/100/21
Pollution Degree (DIN VDE 0110/1.89)		2
Comparative Tracking Index		175

Symbol	Parameter	Value	Unit
V _{PR}	Input-to-Output Test Voltage, Method A, V_{IORM} x 1.6 = V_{PR} , Type and Sample Test with t_m = 10 s, Partial Discharge < 5 pC	1360	V _{peak}
	Input–to–Output Test Voltage, Method B, $V_{IORM}x$ 1.875 = $V_{PR},$ 100% Production Test with t_m = 1 s, Partial Discharge < 5 pC	1594	V _{peak}
VIORM	Maximum Working Insulation Voltage	850	V _{peak}
VIOTM	Highest Allowable Over-Voltage	6000	V _{peak}
	External Creepage	≥7	mm
	External Clearance	≥7	mm
DTI	Distance Through Insulation (Insulation Thickness)	≥0.4	mm
Τ _S	Case Temperature (Note 1)	175	°C
I _{S,INPUT}	Input Current (Note 1)	400	mA
P _{S,OUTPUT}	Output Power (Note 1)	700	mW
R _{IO}	Insulation Resistance at T _S , V _{IO} = 500 V (Note 1)	>10 ⁹	Ω

As per DIN EN/IEC 60747-5-5, this optocoupler is suitable for "safe electrical insulation" only within the safety limit data. Compliance with the safety ratings shall be ensured by means of protective circuits. 1. Safety limit values – maximum values allowed in the event of a failure.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

Symbol	Parameter	Device	Value	Unit
T _{STG}	Storage Temperature	All	-55 to +150	°C
T _{OPR}	Operating Temperature	All	-55 to +100	°C
TJ	Junction Temperature	All	-55 to +125	°C
T _{SOL}	Lead Solder Temperature	All	260 for 10 sec	°C
P _{D(TOTAL)}	Total Device Power Dissipation @ 25°C	All	500	mW
	Derate Above 25°C	All	6.6	mW/°C

EMITTER

١ _F	Continuous Forward Current	All	30	mA
V _R	Reverse Voltage	All	6	V
P _{D(EMITTER)}	Total Power Dissipation 25°C Ambient	All	50	mW
	Derate Above 25°C	All	0.71	mW/°C

DETECTOR

V _{DRM}	Off-State Output Terminal Voltage	FOD420, FOD4216	600	V
		FOD4208, FOD4218	800	
I _{TSM}	Peak Non-Repetitive Surge Current (single cycle 60 Hz sine wave)	All	3	A _{peak}
I _{TM}	Peak On-State Current	All	300	mA _{peak}
P _{D(DETECTOR)}	Total Power Dissipation @ 25°C Ambient	All	450	mW
P _{D(DETECTOR)}	Derate Above 25°C	All	5.9	mW/∘C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Symbol	Parameter	Test Condition	Device	Min	Тур	Max	Unit	

Emitter								
V_{F}	Input Forward Voltage	I _F = 20 mA		All	_	1.28	1.50	V
I _R	Reverse Leakage Current	V _R = 6 V		All	_	0.01	10	μΑ
Detector								
I _{D(RMS)} Peak Blocking Current, Either Direction		$I_F = 0,$ $T_A = 100^{\circ}C$ (Nate 2)	V _D = 600 V	FOD420, FOD4216	-	3	100	μΑ
	(Note 2)	V _D = 800 V	FOD4208, FOD4218]				
I _{R(RMS)}	Reverse Current	T _A = 100°C	V _D = 600 V	FOD420, FOD4216	-	3	100	μA
			V _D = 800 V	FOD4208, FOD4218				
dv/dt	Critical Rate of Rise of Off-State Voltage	I _F = 0 A (Note 3)	$V_D = V_{DRM}$	All	10,000	-	-	V/µs

TRANSFER CHARACTERISTICS

I _{FT}	LED Trigger Current	Main Terminal Vol	tage = 5 V (Note 4)	FOD420, FOD4208	-	0.75	2.0	mA
				FOD4216, FOD4218	-	0.75	1.3	
V _{TM}	Peak On-State Voltage, Either Direction	I _{TM} = 300 mA pea	k, I _F = Rated I _{FT}	All	-	2.2	3	V
Ι _Η	Holding Current, Either Direction	V _T = 3 V		All	-	200	500	μΑ
١L	Latching Current	V _T = 2.2 V		All	_	5	-	mA
t _{ON}	Turn–On Time	PF = 1.0, I _T = 300 mA	V _{RM} = V _{DM} = 424 VAC	FOD420, FOD4216, FOD4218	-	60	-	μs
			$V_{RM} = V_{DM} = 565 \text{ VAC}$	FOD4208				
t _{OFF}	Turn–Off Time		V _{RM} = V _{DM} = 424 VAC	FOD420, FOD4216, FOD4218	-	52	-	μs
			$V_{RM} = V_{DM} = 565 \text{ VAC}$	FOD4208				
dv/dt _C	Critical Rate of Rise of Voltage at Current Commutation	V_D = 230 V_{RMS} , I_D = 300 mA _{PK}		All	-	10	-	V/μs
di/dt _C	Critical Rate of Rise of On-State Current Commutation	$V_D = 230 V_{RMS}, I_D = 300 \text{ mA}_{PK}$		All	-	9	-	A/ms
dv(_{IO})/dt	Critical Rate of Rise of Coupled Input / Output Voltage	I _T = 0 A, V _{RM} = V _E	_{DM} = 424 VAC	All	10,000	-	-	V/μs

ISOLATION CHARACTERISTICS

V _{ISO}	Steady State Isolation Voltage	f = 60 Hz, t = 1 Minute (Note 5)	All	5,000	-	-	VAC _{RMS}
	Vollago						

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Test voltage must be applied within dv/dt rating.

3. This is static dv/dt.. Commutating dv/dt is a function of the load-driving thyristor(s) only.

4. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}. Therefore, recommended operating I_F lies between max I_{FT} (2 mA for FOD420 and FOD4208 and 1.3 mA for FOD4216 and FOD4218) and the absolute max I_F (30 mA).

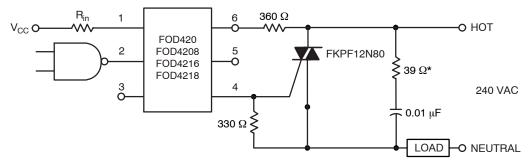
Isolation voltage, V_{ISO}, is an internal device dielectric breakdown rating. For this test, pins 1, 2 and 3 are common, and pins 4, 5 and 6 are common. 5,000 VAC_{RMS} for 1 minute duration is equivalent to 6,000 VAC_{RMS} for 1 second duration.

TYPICAL APPLICATION

Figure 1 shows a typical circuit for when hot line switching is required. In this circuit the "hot" side of the line is switched and the load connected to the cold or neutral side. The load may be connected to either the neutral or hot line.

Rin is calculated so that IF is equal to the rated IFT of the

part, 2 mA for FOD420 and FOD4208, 1.3 mA for FOD4216 and FOD4218. The 39 Ω resistor and 0.01 μ F capacitor are for snubbing of the triac and may or may not be necessary depending upon the particular triac and load use.



*For highly inductive loads (power factor < 0.5), change this value to 360 Ω .

Figure 1. Hot-Line Switching Application Circuit

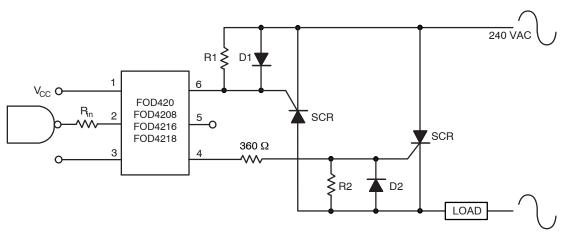
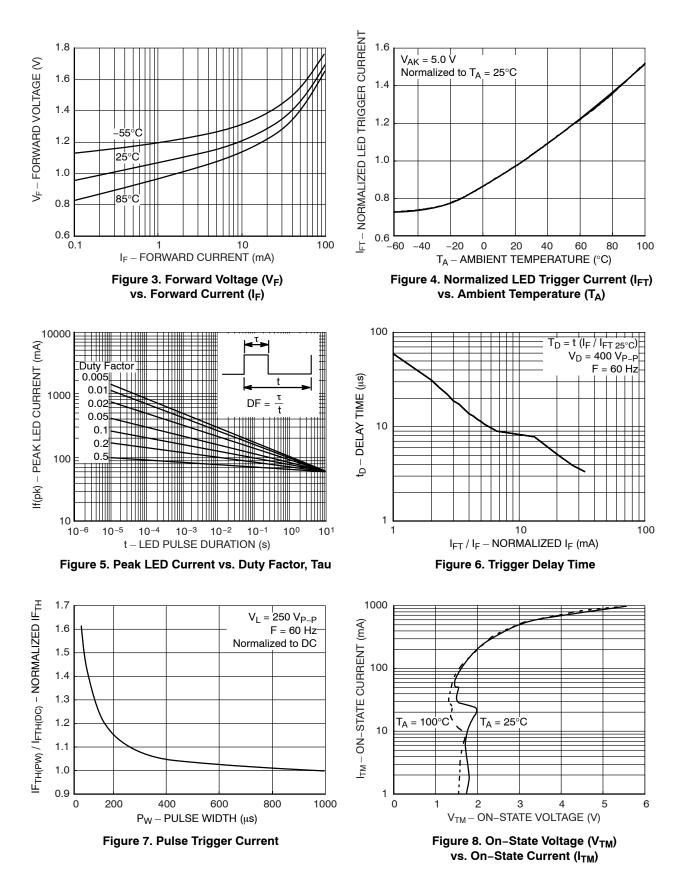


Figure 2. Inverse-Parallel SCR Driver Circuit

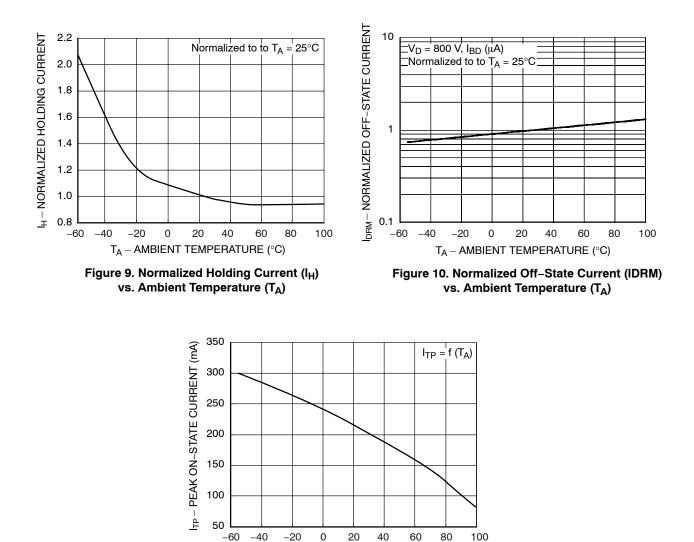
Suggested method of firing two, back-to-back SCR's with On Semiconductor triac driver. Diodes can be 1N4001; resistors, R1 and R2, are optional 330 Ω .

NOTE: This optoisolator should not be used to drive a load directly. It is intended to be a discrete triac driver device only.

TYPICAL CHARACTERISTICS

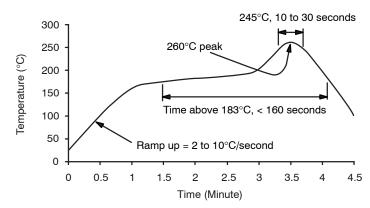


TYPICAL CHARACTERISTICS (continued)



T_A – AMBIENT TEMPERATURE (°C) Figure 11. Current Reduction

REFLOW PROFILE



•Peak reflow temperature: 262°C (package surface temperature) •Time of temperature higher than 183°C for 160 seconds or less •One time soldering reflow is recommended

Figure 12. Reflow Profile

ORDERING INFORMATION

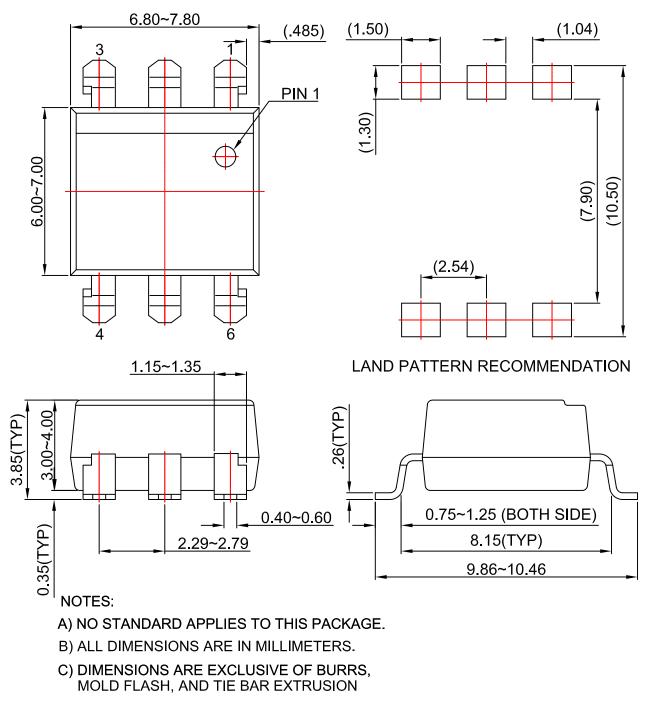
Part Number	Package	Shipping [†]
FOD420	DIP 6-Pin	50 Units / Tube
FOD420S	SMT 6-Pin (Lead Bend)	50 Units / Tube
FOD420SD	SMT 6-Pin (Lead Bend)	1000 / Tape & Reel
FOD420V	OD420V DIP 6-Pin, DIN EN/IEC60747-5-5 Option	
FOD420SV	FOD420SV SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option	
FOD420SDV	FOD420SDV SMT 6-Pin (Lead Bend), DIN EN/IEC60747-5-5 Option	
FOD420TV	DIP 6-Pin, 0.4" Lead Spacing, DIN EN/IEC60747-5-5 Option	50 Units / Tube

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. 6. The product orderable part number system listed in this table also applies to the FOD4208, FOD4216, and FOD4218product families.



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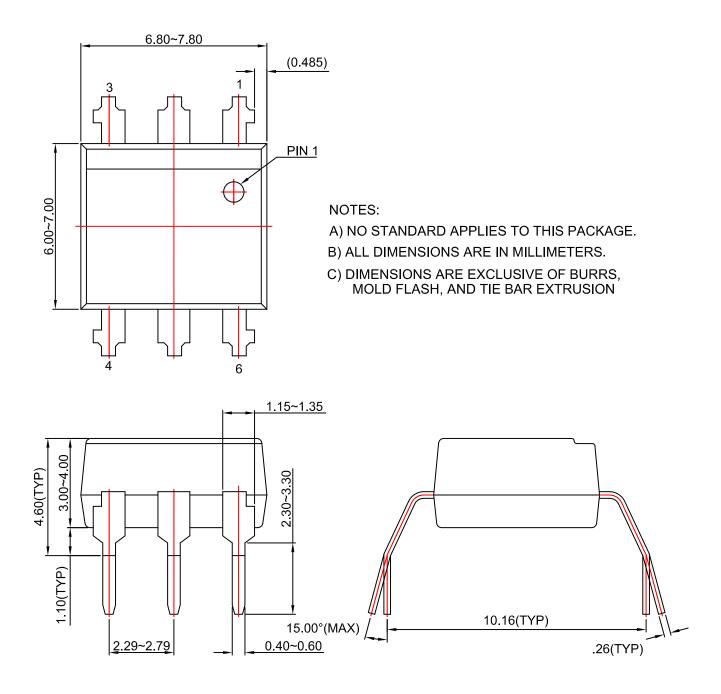
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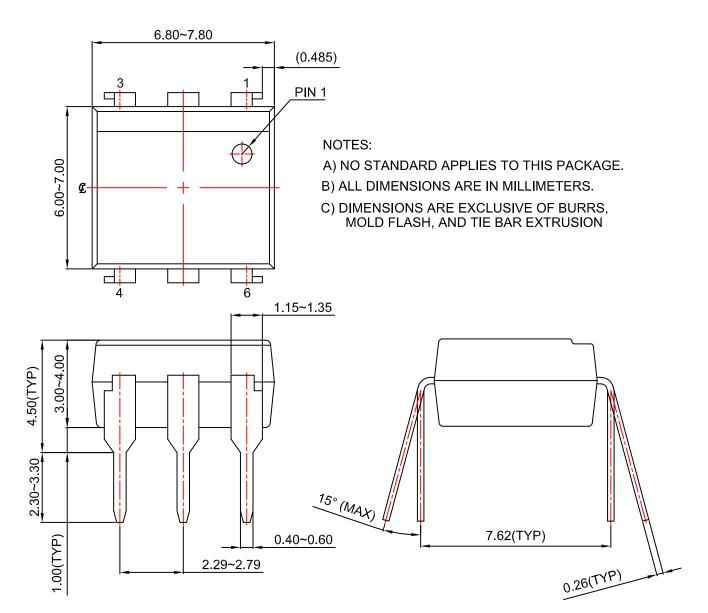
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